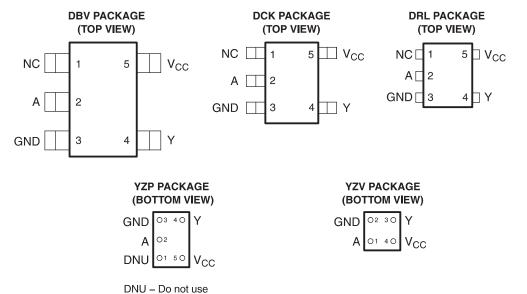


SCES295T-JUNE 2000-REVISED JANUARY 2007

### FEATURES

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Input and Open-Drain Output Accept Voltages up to 5.5 V
- Max t<sub>nd</sub> of 4 ns at 3.3 V
- Low Power Consumption, 10- $\mu$ A Max I<sub>CC</sub>

- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A) \_
  - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

### **DESCRIPTION/ORDERING INFORMATION**

This single inverter buffer/driver is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

The output of the SN74LVC1G06 device is open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32 mA.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

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#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>	
(	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC1G06YZPR	CT_	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZV (Pb-free)	Reel of 3000	SN74LVC1G06YZVR	<u>c</u> t	
–40°C to 85°C		Reel of 3000	SN74LVC1G06DBVR	000	
	SOT (SOT-23) – DBV	Reel of 250	SN74LVC1G06DBVT	C06_	
		Reel of 3000	SN74LVC1G06DCKR	07	
	SOT (SC-70) – DCK	Reel of 250	SN74LVC1G06DCKT	CT_	
	SOT (SOT-553) – DRL	Reel of 4000	SN74LVC1G06DRLR	CT_	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DBV/DCK/DRL: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free). YZV: The actual top-side marking is on two lines. Line 1 has four characters to denote year, month, day, and assembly/test site. Line 2 has two characters which show the family and function code. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

СІ	INI	сτ		ТΙ	• ^ 1	BLE
гι	лл	CI.	IUI	NI	A	DLC

INPUT A	OUTPUT Y
Н	L
L	н

#### LOGIC DIAGRAM (POSITIVE LOGIC) (DBV, DCK, DRL, YZP PACKAGE)



LOGIC DIAGRAM (POSITIVE LOGIC) (YZV PACKAGE)

SCES295T-JUNE 2000-REVISED JANUARY 2007

### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	6.5	V	
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>				V	
Vo	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>				V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
I <sub>O</sub>	Continuous output current		±50	mA		
	Continuous current through $V_{CC}$ or GND	)		±100	mA	
		DBV package		206		
		DCK package		252		
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DRL package		142		
		YZP package		132		
		YZV package		123		
T <sub>stg</sub>	Storage temperature range	-65	150	°C		

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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### **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT	
V	Supply voltage	Operating	1.65	5.5	V	
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		v	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$			
.,		$V_{CC}$ = 2.3 V to 2.7 V	1.7		V	
V <sub>IH</sub>	High-level input voltage	$V_{CC}$ = 3 V to 3.6 V	2		V	
		$V_{CC}$ = 4.5 V to 5.5 V	$0.7  imes V_{CC}$			
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
		$V_{CC}$ = 2.3 V to 2.7 V		0.7	V	
V <sub>IL</sub> Low	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		0.8	V	
		$V_{CC}$ = 4.5 V to 5.5 V		$0.3  imes V_{CC}$		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	5.5	V	
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8		
OL	Low-level output current	<u> </u>		16	mA	
		$V_{CC} = 3 V$		24		
		V <sub>CC</sub> = 4.5 V		32		
		$V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20		
∆t/∆v	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		$V_{CC} = 5 V \pm 0.5 V$		5		
Γ <sub>A</sub>	Operating free-air temperature	· · · · · · · · · · · · · · · · · · ·	-40	85	°C	

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARA	AMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup> MAX	UNIT		
		I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V	0.1			
		$I_{OL} = 4 \text{ mA}$	1.65 V	0.45			
M		I <sub>OL</sub> = 8 mA	2.3 V	0.3	V		
V <sub>OL</sub>		I <sub>OL</sub> = 16 mA	2.1/	0.4	v		
		$I_{OL} = 24 \text{ mA}$	3 V	0.55			
		I <sub>OL</sub> = 32 mA	4.5 V	0.55			
l <sub>l</sub>	A input	$V_{I} = 5.5 \text{ V or GND}$	0 to 5.5 V	±1	μA		
I <sub>off</sub>		$V_{I}$ or $V_{O} = 5.5 V$	0	±10	μA		
I <sub>CC</sub>		$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V	10	μA		
$\Delta I_{CC}$		One input at $V_{CC} - 0.6 V$ , Other inputs at $V_{CC}$ or GND	3 V to 5.5 V	500	μA		
Ci		$V_{I} = V_{CC}$ or GND	3.3 V	4	pF		
Co		$V_{O} = V_{CC} \text{ or } GND$	3.3 V	5	pF		

(1) All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.



SCES295T-JUNE 2000-REVISED JANUARY 2007

#### **Switching Characteristics**

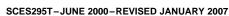
over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		$V_{CC}$ = 2.5 V $\pm$ 0.2 V		$V_{CC} = 3.3 V \\ \pm 0.3 V$		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y	2.2	6.5	1.1	4	1.2	4	1	3	ns

### **Operating Characteristics**

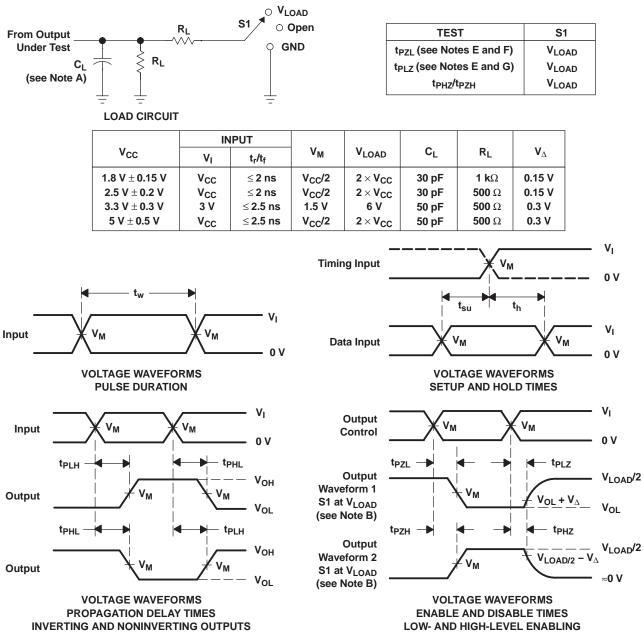
 $T_A = 25^{\circ}C$ 

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC} = 2.5 V$	$V_{CC} = 3.3 V$	$V_{CC} = 5 V$	V UNIT	
		TEST CONDITIONS	TYP	TYP	TYP	TYP		
C <sub>pd</sub> Power dis	sipation capacitance	f = 10 MHz	3	3	4	6	pF	





### PARAMETER MEASUREMENT INFORMATION (OPEN DRAIN)



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. Since this device has open-drain outputs,  $t_{\mathsf{PLZ}}$  and  $t_{\mathsf{PZL}}$  are the same as  $t_{\mathsf{pd}}$
- F.  $t_{PZL}$  is measured at V<sub>M</sub>.
- G.  $t_{PLZ}$  is measured at  $V_{OL} + V_{\Delta}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms

8-Dec-2008

### **PACKAGING INFORMATION**

**FRUME** 

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74LVC1G06DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G06YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74LVC1G06YZVR	ACTIVE	DSBGA	YZV	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

# PACKAGE OPTION ADDENDUM



<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC1G06 :

Enhanced Product: SN74LVC1G06-EP

NOTE: Qualified Version Definitions:

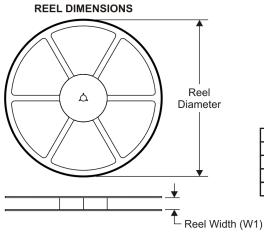
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

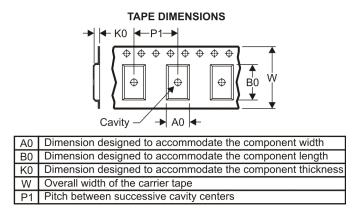
# PACKAGE MATERIALS INFORMATION

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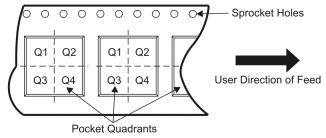
Texas Instruments

### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	All dimensions are nominal											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DCKR	SC70	DCK	5	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G06DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DCKR	SC70	DCK	5	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DRLR	SOT	DRL	5	4000	180.0	9.2	1.78	1.78	0.69	4.0	8.0	Q3
SN74LVC1G06YZPR	DSBGA	YZP	5	3000	180.0	8.4	1.02	1.52	0.63	4.0	8.0	Q1
SN74LVC1G06YZVR	DSBGA	YZV	4	3000	180.0	8.4	1.02	1.02	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

28-Oct-2009



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G06DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G06DCKR	SC70	DCK	5	3000	205.0	200.0	33.0
SN74LVC1G06DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G06DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74LVC1G06DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G06YZPR	DSBGA	YZP	5	3000	220.0	220.0	34.0
SN74LVC1G06YZVR	DSBGA	YZV	4	3000	220.0	220.0	34.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE

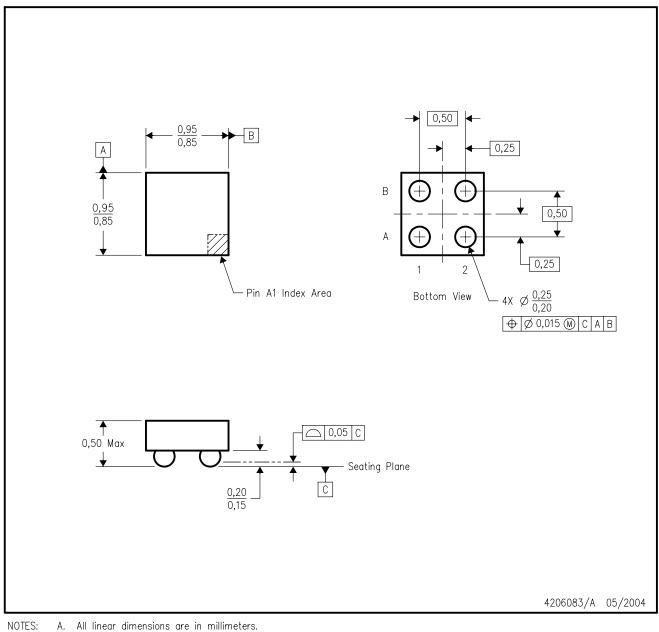


- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AA.



YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package contains lead-free balls. Refer to the 4 YEV package (drawing 4206082) for tin-lead (SnPb) balls.

NanoFree is a trademark of Texas Instruments.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

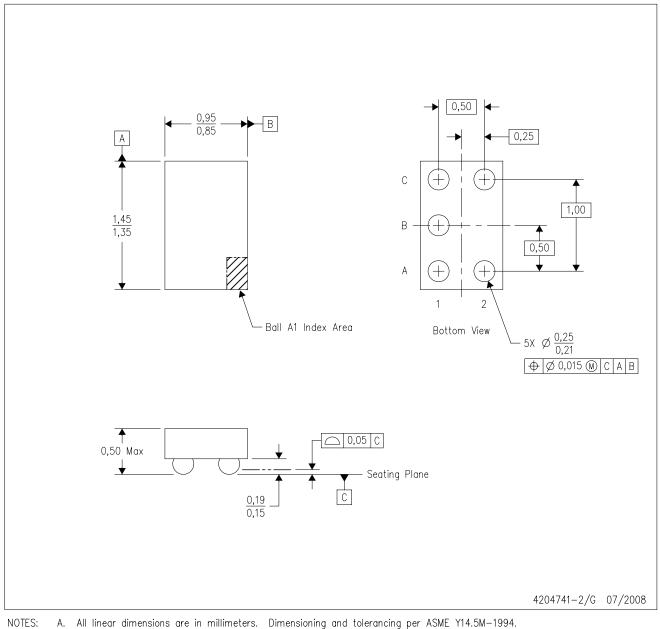
🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



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